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Time: Three Hours] [Maximum Marks: 100

Note: Attempt Five questions in all, selecting at least one question from each Unit.

## Unit I

- (a) Draw the schematic diagram of the production of electronic grade silicon from the hydrogen reduction of trichlorosilane.
  - (b) Write DC sputtering thin film deposition technique and its limitations.10
- 2. Describe any four of the following: 20
  - (a) Oxidation Induced Defects
  - (b) Orientation dependence oxidation rate
  - (c) Oxide Charges
  - (d) Epitaxial Defects
  - (e) Why Boron concentration at tail end in CZ grown crystals is larger than seed end?

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## Unit II

- (a) Explain X-ray source, X-ray mask and photo resist challenges for hthography of VLSI circuits.
  - (b) Describe various oxide charges, its effect on device performance, and techniques to minimize its effects.

4. (a) Describe AC Plasma excitation and explain etch rate of Silicon in CF<sub>4</sub> + O<sub>2</sub> plasma with percentage
 O<sub>2</sub> concentration. http://www.kuonline.in
 10

(b) Describe E-beam lithographic technique for pattern writing and mask making.
10

## **Unit III**

- (a) Describe Channeling and methods to stop channeling and also significance of post-implant annealing. 10
  - (b) Discuss diffusion profile measurement techniques.
- (a) Explain basic diffusion mechanism in solids, and
  Fick's law of diffusion and its solution for the
  Constant total dopant's.
  - (b) Describe Ion implantation and range theory. 10

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## **Unit IV**

7.	Write short notes on the following:						
	(a)	Double	${\bf diffusion}$	BJT	IC	fabrication	process
		sequence	:				10
	(b)	Dielectric Isolation					5
	(c)	Constraints in MEMS packaging.					5

- 8. Write short notes on any four of the following:
  - (a) Twin tub CMOS fabrication technology and mask requirements
  - (b) Describe various package design considerations
  - (c) Trench Isolation Technique
  - (d) Semi-recessed LOCOS and bird's beak encroachment
  - (e) Bipolar IC fabrication in brief.

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